



60V PNP MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Features

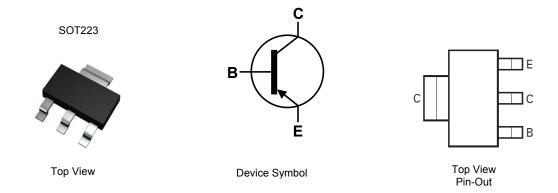
- BV_{CEO} > -60V
- I_C = -5.5A High Continuous Collector Current
- I_{CM} = -15A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -70mV @ -1A
- $R_{SAT} = 39m\Omega$ for a Low Equivalent On-Resistance
- hFE Specified Up to -10A for a High Gain Hold Up
- Complementary NPN Type: ZX5T851G
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)

Applications

- DC-DC converters
- MOSFET & IGBT gate drivers
- Charging circuits
- Power switches
- Motor control



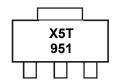
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T951GTA	X5T951	7	12	1,000
ZX5T951GTC	X5T951	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

Marking Information



X5T951 = Product type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-100	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-5.5	Α
Peak Pulse Current	I _{CM}	-15	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol Value		Unit		
Power Dissipation	(Note 5)	,	3.0 24	W mW /°C	
Linear derating factor	(Note 6)	P _D	1.6 12.8		
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ heta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 7)		$R_{ heta JL}$	10.48		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

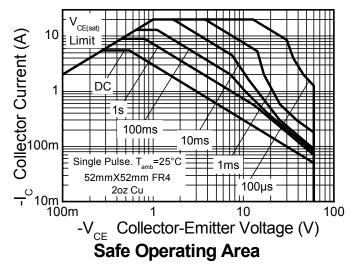
Notes:

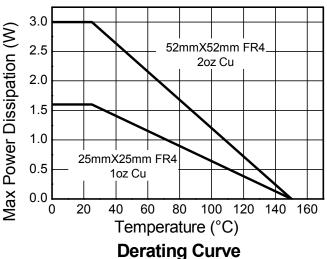
- 5. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as note (5), except the device is surface mounted on 25mm x 25mm with 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

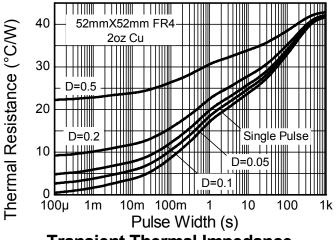


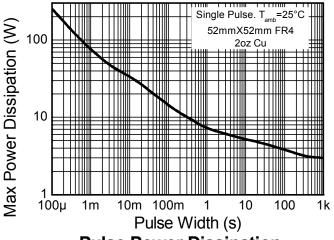


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



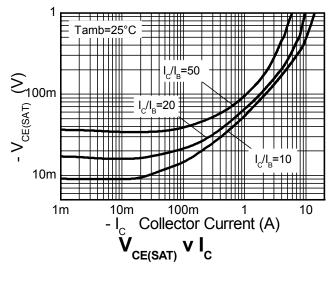
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

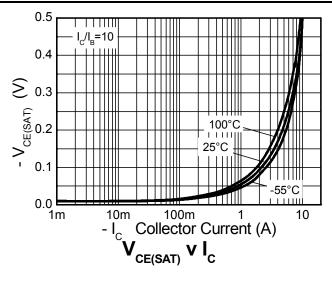
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	-100	-120	-	V	$I_C = -1\mu A$, RB $\leq 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV_EBO	-7	-8.1	-	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	-	<1 -	-20 -0.5	nΑ μΑ	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Collector-Emitter Cutoff Current	l _{CER} R ≤ 1kΩ	-	<1 -	-20 -0.5	nΑ μΑ	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	V _{EB} = -6V
		100	250	-	-	$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
Static Forward Current Transfer Ratio (Note 9)	h	100	200	300		I _C = -2A, V _{CE} = -1V
Static Folward Current Transfer Ratio (Note 9)	h _{FE}	45	90	-		$I_C = -5A$, $V_{CE} = -1V$
		10	25	-		$I_C = -10A$, $V_{CE} = -1V$
		-	-15	-25	mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	\/	-	-55	-70		$I_C = -1A$, $I_B = -100mA$
Collector-Emitter Saturation voltage (Note 9)	$V_{CE(sat)}$	-	-90	-120	IIIV	$I_C = -2A$, $I_B = -200mA$
		-	-195	-250		$I_C = -5A$, $I_B = -500mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	-1030	-1150	mV	$I_C = -5A$, $I_B = -500$ mV
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	-	-920	-1020	mV	I _C = -5A, V _{CE} = -1V
Output Capacitance (Note 9)	C_obo	-	48	-	pF	V_{CB} = -10V. f = 1MHz
Transition Frequency	f _T	-	120	-	MHz	$V_{CE} = -10V, I_{C} = -100mA$ f = 50MHz
Switching Time	t _{on}	-	39	-	ns	V _{CC} = -10V, I _C = -1A
Owitering Time	t_{off}	-	370	-	115	$I_{B1} = -I_{B2} = -100 \text{mA}$

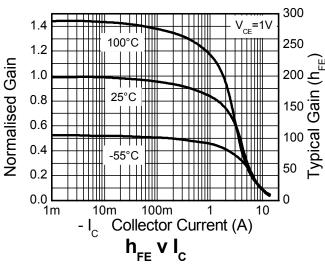
Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

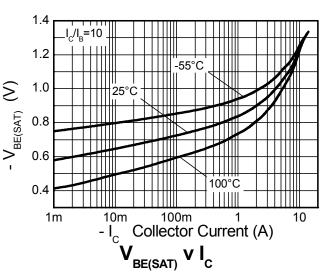


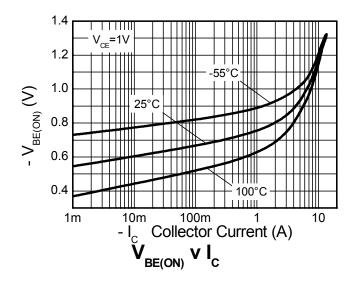
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







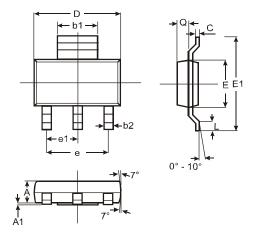






Package Outline Dimensions

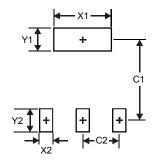
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3





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